



1-Line Bi-directional low Capacitance TVS Diode

Description

The SSCE5V0C2N1 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The SSCE5V0C2N1 has an ultra-low capacitance with a typical value at 0.15 pF, and complies with the IEC 61000-4-2 (ESD) with ±20kV air and ±15kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package.

Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, USB 3.0 and USB 4.0 super speed, VGA, DVI, HDMI, SDI and other high speed line applications.

Features

- ♦ 40W peak pulse power (t_P = 8/20µs)
- ♦ DFN1006-2L Package
- ♦ Working voltage:5V
- ♦ Low Leakage Current
- ♦ Low capacitance
- ♦ Low clamping voltage
- ♦ Response Time is Typically<1ns</p>
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±20kV

Contact discharge: ±15kV

-IEC61000-4-5(Lightning)2.5A(8/20µs)

Mechanical Characteristics

♦ Package: DFN1006-2L (1.0×0.6×0.5mm)

♦ Lead finish: 100% matte Sn (Tin)

♦ Device meets MSL 3 requirements

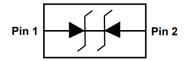
Case Material: "Green" Molding Compound.

♦ RoHS Compliant

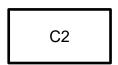
PIN configuration



DFN1006-2L (Bottom View)



Circuit Diagram



Marking (Top View)

Applications

- ♦ DVI & HDMI Port Protection
- USB 2.0, USB 3.0 and USB 4.0
- ♦ SATA and eSATA
- ♦ Serial and Parallel Ports
- ♦ Projection TV
- Notebooks, Desktops, Servers
- ♦ Digital cameras

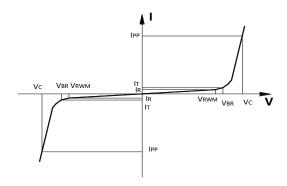
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• Electronic Parameter

| Symbol | Parameter | | |
|-----------------|--|--|--|
| V_{RWM} | Peak Reverse Working Voltage | | |
| I _R | Reverse Leakage Current @ V _{RWM} | | |
| V _{BR} | Breakdown Voltage @ I⊤ | | |
| I _T | Test Current | | |
| IPP | Maximum Reverse Peak Pulse Current | | |
| Vc | Clamping Voltage @ IPP | | |
| P _{PP} | Peak Pulse Power | | |
| Сл | Junction Capacitance | | |



Absolute maximum rating (T_A=25[°]C unless otherwise noted)

| Parameter | | Symbol | Value | Units | |
|------------------------------|-----------------|------------------|----------|---------------|--|
| Peak Pulse Power(8/20µs) | | P _{PP} | 40 | W | |
| Peak Pulse Current (8/20µs) | I _{PP} | 2.5 | Α | | |
| ESD Rating per IEC61000-4-2: | Contact | Vesd | ±15 | kV | |
| | Air | VESD | ±20 | | |
| Storage Temperature | | T _{STG} | -55/+150 | ${\mathbb C}$ | |
| Operating Temperature | | TJ | -55/+125 | ${\mathbb C}$ | |

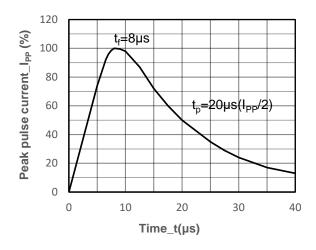
• Electrical Characteristics (T_A=25℃ unless otherwise noted)

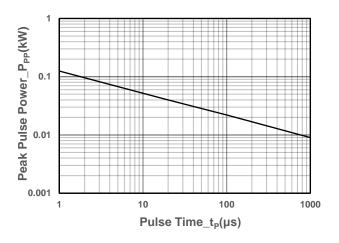
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|------------------------------|------------------|------------------------------------|------|------|------|-------|
| Peak Reverse Working Voltage | V _{RWM} | | | | 5 | V |
| Breakdown Voltage | V_{BR} | I _T = 1mA | 6 | | 9 | V |
| Reverse Leakage Current | I _R | V _{RWM} = 5V | | | 0.1 | μA |
| Clamping Voltage | Vc | $I_{PP} = 1A$, $t_P = 8/20 \mu s$ | | 10 | 12 | V |
| Clamping Voltage | Vc | $I_{PP} = 2.5A, t_P = 8/20 \mu s$ | | 13 | 16 | V |
| Dynamic resistance | R _{DYN} | | | 0.26 | | Ω |
| Junction Capacitance | Сл | $V_R = 0V$, $f = 1MHz$ | | 0.15 | 0.18 | pF |

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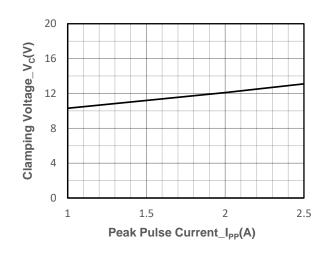
• Typical Performance Characteristics (T_A=25℃ unless otherwise noted)

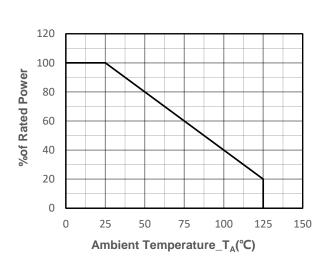




8/20µs Pulse Waveform

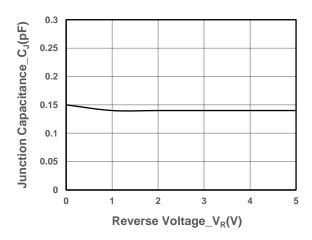
Peak Pulse Power vs. Pulse Time

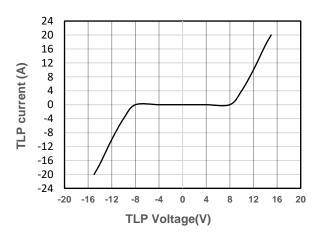




Clamping Voltage vs. Peak Pulse Current

Power derating vs. Ambient temperature





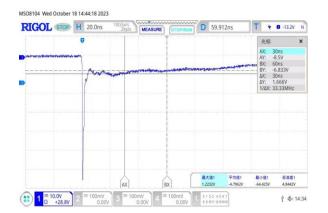
Junction Capacitance vs. Reverse Voltage

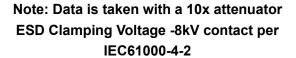
TLP Measurement

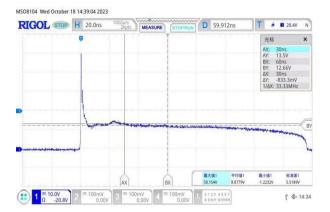
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• Typical Performance Characteristics (TA=25°C unless otherwise noted)







Note: Data is taken with a 10x attenuator ESD Clamping Voltage 8kV contact per IEC61000-4-2



Package Information

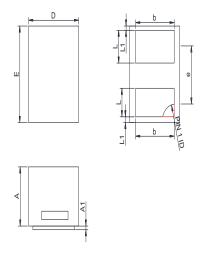
Ordering Information

| Device | Package | Qty per Reel | Reel Size |
|-------------|------------|--------------|-----------|
| SSCE5V0C2N1 | DFN1006-2L | 10000 | 7 Inch |

Mechanical Data

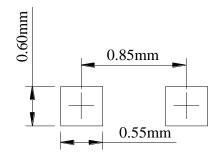
Case: DFN1006-2L

Case Material: Molded Plastic. UL Flammability



| DIM | Millimeters | | | |
|------------|-------------|------|--|--|
| DIIVI | Min | Max | | |
| Α | 0.45 | 0.55 | | |
| A 1 | 0.00 | 0.05 | | |
| D | 0.55 | 0.65 | | |
| E | 0.95 | 1.05 | | |
| b | 0.45 | 0.60 | | |
| е | 0.65TYP | | | |
| L | 0.2 | 0.3 | | |
| L1 | 0.05REF | | | |

Suggested Land Pattern



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SSCE5V0C2N1

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